NPN Triple Diffused Planar Silicon Transistor



2SC4597

Switching Regulator Applications

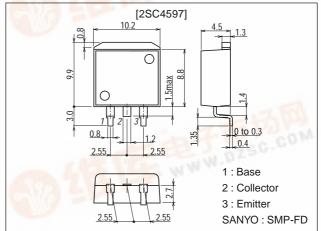
Features

- · Surface mount type device making the following possible.
- -Reduction in the number of manufacturing processes for 2SC4597-applied equipment.
- -High density surface mount applications.
- -Small size of 2SC4597-applied equipment.
- · High breakdown voltage, high reliability.
- · Fast switching speed.
- · Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit:mm

2069C



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V _{CBO}		500	V	
Collector-to-Emitter Voltage	V _{CEO}		400	V	
Emitter-to-Base Voltage	V _{EBO}	110	7	V	
Collector Current	lc		4	Α	
Collector Current (Pulse)	I _{CP}	PW≤300μs, duty cycle≤10%	8	Α	
Base Current	I _B		1.5	Α	
Collector Dissipation	PC		1.65	W	
		Tc=25°C	40	W	
Junction Temperature	Tj	D Last	150	°C	
Storage Temperature	Tstg	- Com	-55 to +150	°C	

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =400V, I _E =0			10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.4A	15*	M 107	50*	T.
	h _{FE} 2	V _{CE} =5V, I _C =2A	10			
	h _{FE} 3	V _{CE} =5V, I _C =10mA	10			

^{*:} For the h_{FE}1 of the 2SC4597, specify two ranks or more in principle.

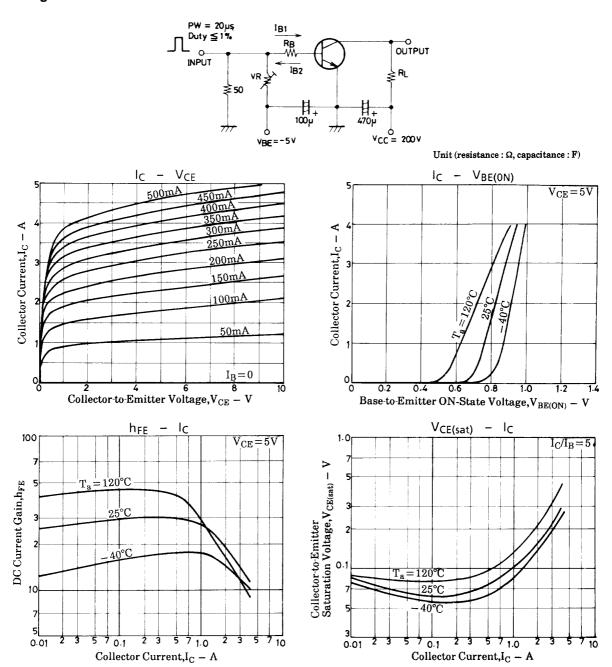
15 L 30 20 M 40 30 N 50

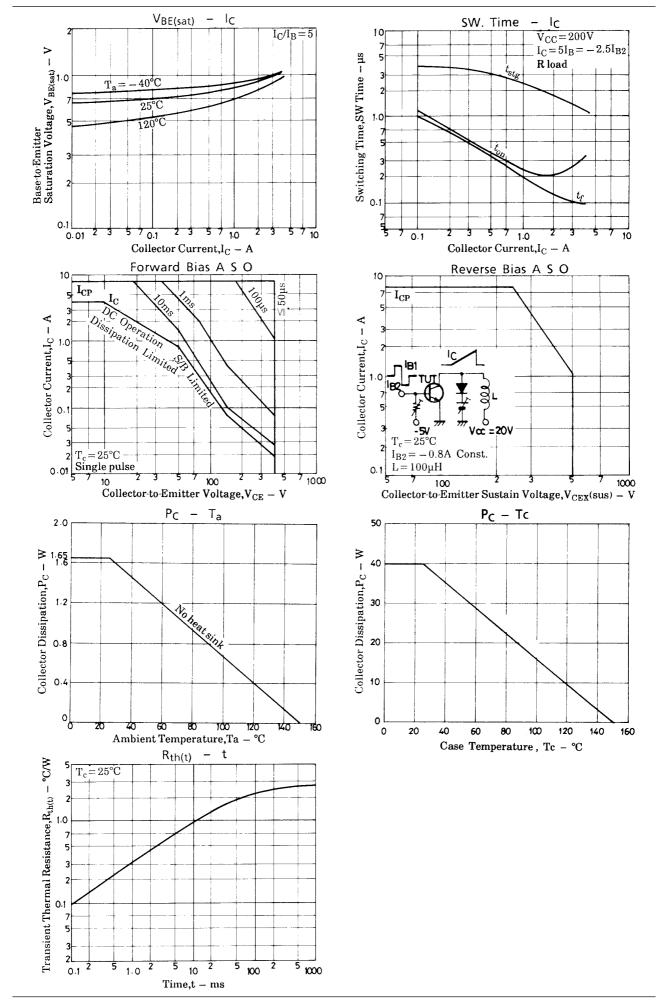
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.4A		20		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		50		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =2A, I _B =0.4A			0.8	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =2A, I _B =0.4A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	VCEX(sus)	I _C =2A, I _{B1} =0.2A, L=1mH, I _{B2} =-0.8A, clamped	400			V
Turn-ON Time	ton	I_{C} =3A, I_{B1} =0.6A, I_{B2} =-1.2A, R_{L} =66.6 Ω , V_{CC} =200 V			0.5	μs
Storage Time	t _{stg}	I_{C} =3A, I_{B1} =0.6A, I_{B2} =-1.2A, R_{L} =66.6 Ω , V_{CC} =200 V			2.5	μs
Fall Time	t _f	I_{C} =3A, I_{B1} =0.6A, I_{B2} =-1.2A, R_{L} =66.6 Ω , V_{CC} =200 V			0.3	μs

Switching Time Test Circuit





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